

ROHS COMPLIANT

HALOGEN

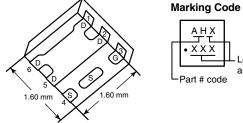
FREE

Vishay Siliconix

N-Channel 30 V (D-S) MOSFET

PRODUCT SUMMARY									
V _{DS} (V)	R_{DS(on)} (Ω)	I _D (A) ^a	Q _g (Typ.)						
	0.042 at V _{GS} = 4.5 V	9							
30	0.046 at V _{GS} = 2.5 V	9	5.7 nC						
	0.052 at V _{GS} = 1.8 V	9							

PowerPAK SC-75-6L-Single



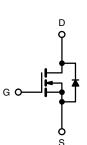
_ot Traceability and Date code

FEATURES

- TrenchFET[®] Power MOSFET
- 100 % R_g Tested
- Material categorization: For definitions of compliance please see www.vishay.com/doc?99912

APPLICATIONS

- DC/DC Converters
- **Boost Converters**



N-Channel MOSFET

Ordering Information:

SiB410DK-T1-GE3 (Lead (Pb)-free and Halogen-free)

Parameter		Symbol	Limit	Unit		
Drain-Source Voltage		V _{DS}	30			
Gate-Source Voltage		V _{GS}	± 8	V		
	T _C = 25 °C		9 ^a			
Continuous Drain Current (T _J = 150 °C)	T _C = 70 °C		9 ^a			
Continuous Diam Current $(1) = 150^{\circ}$ C)	T _A = 25 °C	I _D	5.9 ^{b, c}			
	T _A = 70 °C		4.7 ^{b, c}	A		
Pulsed Drain Current		I _{DM}	20			
Continuous Source-Drain Diode Current	T _C = 25 °C		9 ^a			
Continuous Source-Drain Diode Current	T _A = 25 °C	I _S	2.1 ^{b, c}			
	T _C = 25 °C		13			
Maximum Power Dissipation	T _C = 70 °C	P _D	8.4	w		
Maximum Fower Dissipation	T _A = 25 °C		2.5 ^{b, c}			
	T _A = 70 °C	1 [1.6 ^{b, c}			
Operating Junction and Storage Temperatur	T _J , T _{stg}	- 55 to 150	°C			
Soldering Recommendations (Peak Temperations	ature) ^{d, e}		260			

THERMAL RESISTANCE RATINGS									
Parameter		Symbol	Typical	Maximum	Unit				
Maximum Junction-to-Ambient ^{b, f}	o-Ambient ^{b, f} $t \le 5$ s R_{thJA} 41 51		°C/W						
Maximum Junction-to-Case (Drain)	Steady State	R _{thJC}	7.5	9.5	0/11				

Notes:

a. Package limited, $T_C = 25$ °C.

b. Surface mounted on 1" x 1" FR4 board.

c. t = 5 s.

d. See solder profile (www.vishay.com/doc?73257). The PowerPAK SC-75 is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection.

e. Rework conditions: manual soldering with a soldering iron is not recommended for leadless components.

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f. Maximum under steady state conditions is 105 °C/W.

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Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit
Static						
Drain-Source Breakdown Voltage	V _{DS}	$V_{GS} = 0 \text{ V}, \text{ I}_{D} = 250 \mu\text{A}$	30			V
V _{DS} Temperature Coefficient	$\Delta V_{DS}/T_{J}$			31		
V _{GS(th)} Temperature Coefficient	$\Delta V_{GS(th)}/T_J$	I _D = 250 μA		- 2.7		mV/°C
Gate-Source Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}$, $I_D = 250 \ \mu A$	0.4		1	V
Gate-Source Leakage	I _{GSS}	$V_{DS} = 0 V, V_{GS} = \pm 8 V$			± 100	nA
Zara Cata Valtaga Drain Current	la e e	$V_{DS} = 30 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$			1	μA
Zero Gate Voltage Drain Current	IDSS	$V_{DS} = 30 \text{ V}, V_{GS} = 0 \text{ V}, \text{ T}_{J} = 55 ^{\circ}\text{C}$			10	
On-State Drain Current ^a	I _{D(on)}	$V_{DS} \ge 5 \text{ V}, \text{ V}_{GS} = 10 \text{ V}$	10			А
		$V_{GS} = 4.5 \text{ V}, \text{ I}_{D} = 3.8 \text{ A}$		0.034	0.042	
Drain-Source On-State Resistance ^a	R _{DS(on)}	$V_{GS} = 2.5 \text{ V}, \text{ I}_{D} = 3.6 \text{ A}$		0.038	0.046	Ω
		$V_{GS} = 1.8 \text{ V}, \text{ I}_{D} = 2 \text{ A}$		0.041	0.052	1
Forward Transconductance ^a	9 _{fs}	V _{DS} = 15 V, I _D = 3.8 A		30		S
Dynamic ^b	•					•
Input Capacitance	C _{iss}			560		pF
Output Capacitance	C _{oss}	V_{DS} = 15 V, V_{GS} = 0 V, f = 1 MHz		60		
Reverse Transfer Capacitance	C _{rss}			27		
Tatal Cata Charge	0	$V_{DS} = 15 \text{ V}, \text{ V}_{GS} = 8 \text{ V}, \text{ I}_{D} = 3.4 \text{ A}$		10	15	nC
Total Gate Charge	Qg			5.7	8.6	
Gate-Source Charge	Q _{gs}	V_{DS} = 15 V, V_{GS} = 4.5 V, I_{D} = 3.4 A		0.85		
Gate-Drain Charge	Q _{gd}			0.75		
Gate Resistance	R _g	f = 1 MHz	0.6	3	6	Ω
Turn-On Delay Time	t _{d(on)}			6	12	
Rise Time	t _r	V_{DD} = 15 V, R_L = 4.3 Ω		10	20	- - ns
Turn-Off Delay Time	t _{d(off)}	$\text{I}_\text{D}\cong$ 3.5 A, V_GEN = 4.5 V, R_g = 1 Ω		20	40	
Fall Time	t _f			10	20	
Turn-On Delay Time	t _{d(on)}			5	10	
Rise Time	t _r	V_{DD} = 15 V, R_L = 4.3 Ω		10	20	
Turn-Off Delay Time	t _{d(off)}	$\text{I}_\text{D}\cong$ 3.5 A, V_GEN = 8 V, R_g = 1 Ω		17	30	
Fall Time	t _f			10	20	
Drain-Source Body Diode Characteristic	s			•		•
Continuous Source-Drain Diode Current	۱ _S	T _C = 25 °C			1.5	۸
Pulse Diode Forward Current	I _{SM}				20	A
Body Diode Voltage	V _{SD}	I _S = 3.5 A, V _{GS} = 0 V		0.8	1.2	V
Body Diode Reverse Recovery Time	t _{rr}			15	30	ns
Body Diode Reverse Recovery Charge	Q _{rr}			6	12	nC
Reverse Recovery Fall Time	t _a	$I_F = 3.5 \text{ A}, \text{ dI/dt} = 100 \text{ A/}\mu\text{s}, \text{ T}_J = 25 ^\circ\text{C}$		8		
Reverse Recovery Rise Time	t _b			7		ns

Notes:

a. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %

b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

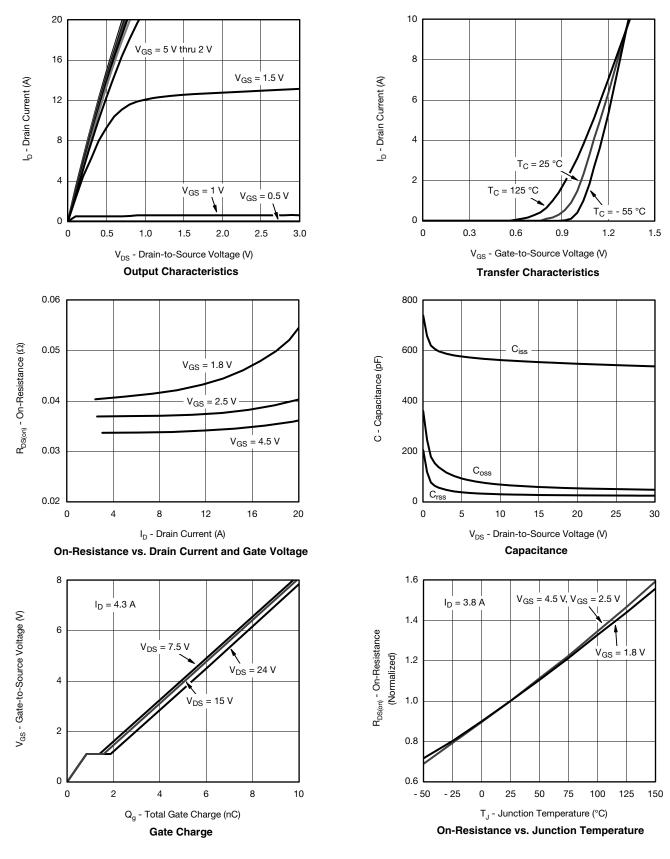
Document Number: 67020 S13-0630-Rev. B, 25-Mar-13

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TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



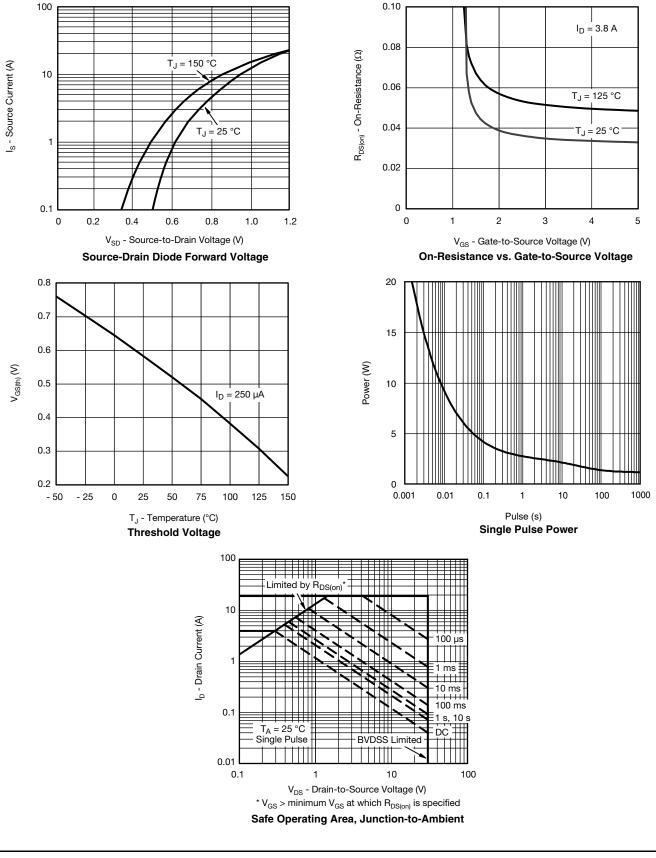
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TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)

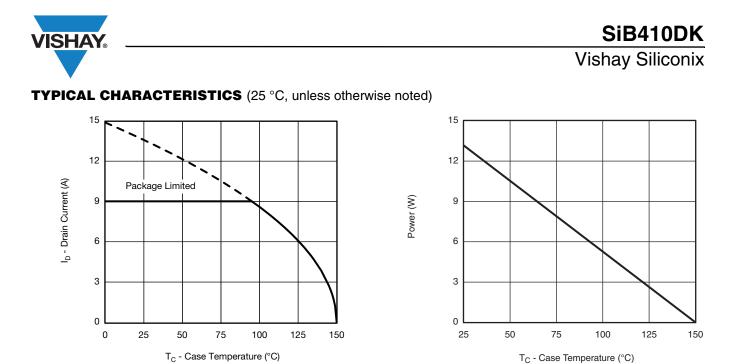


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* The power dissipation P_D is based on $T_{J(max)} = 150$ °C, using junction-to-case thermal resistance, and is more useful in settling the upper dissipation limit for cases where additional heatsinking is used. It is used to determine the current rating, when this rating falls below the package limit.

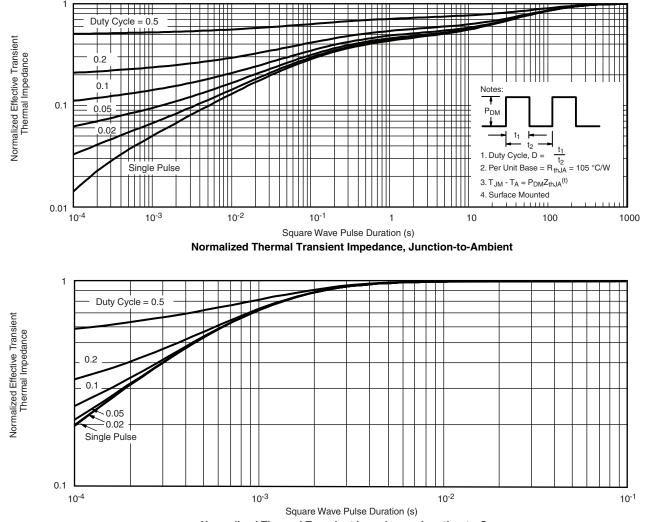
Current Derating*

Power Derating

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TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Case

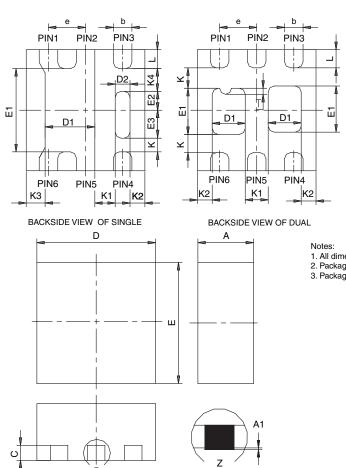
Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg?67020.

Package Information

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PowerPAK[®] SC75-6L



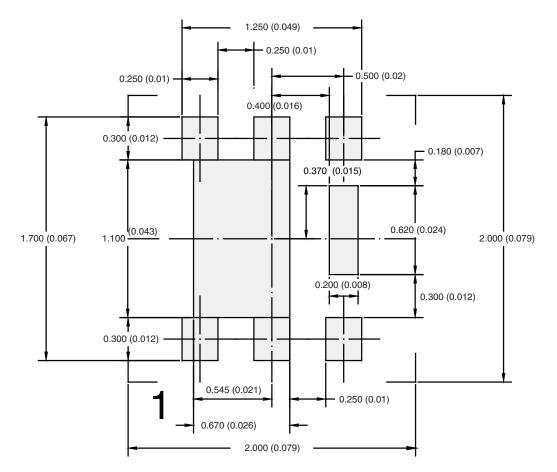
All dimensions are in millimeters
Package outline exclusive of mold flash and metal burr
Package outline inclusive of plating

DETAIL Z

	SINGLE PAD						DUAL PAD					
DIM	М	ILLIMETER	RS		INCHES		М	MILLIMETERS			INCHES	
	Min	Nom	Max	Min	Nom	Max	Min	Nom	Max	Min	Nom	Max
Α	0.675	0.75	0.80	0.027	0.030	0.032	0.675	0.75	0.80	0.027	0.030	0.032
A1	0	-	0.05	0	-	0.002	0	-	0.05	0	-	0.002
b	0.18	0.25	0.33	0.007	0.010	0.013	0.18	0.25	0.33	0.007	0.010	0.013
С	0.15	0.20	0.25	0.006	0.008	0.010	0.15	0.20	0.25	0.006	0.008	0.010
D	1.53	1.60	1.70	0.060	0.063	0.067	1.53	1.60	1.70	0.060	0.063	0.067
D1	0.57	0.67	0.77	0.022	0.026	0.030	0.34	0.44	0.54	0.013	0.017	0.021
D2	0.10	0.20	0.30	0.004	0.008	0.012						
E	1.53	1.60	1.70	0.060	0.063	0.067	1.53	1.60	1.70	0.060	0.063	0.067
E1	1.00	1.10	1.20	0.039	0.043	0.047	0.51	0.61	0.71	0.020	0.024	0.028
E2	0.20	0.25	0.30	0.008	0.010	0.012						
E3	0.32	0.37	0.42	0.013	0.015	0.017						
е		0.50 BSC			0.020 BSC		0.50 BSC			0.020 BSC		
K		0.180 TYP			0.007 TYP		0.245 TYP			0.010 TYP		
K1		0.275 TYP			0.011 TYP		0.320 TYP			0.013 TYP		
K2		0.200 TYP			0.008 TYP		0.200 BSC			0.008 TYP		
K3	0.255 TYP 0.010 TYP											
K4	0.300 TYP			0.012 TYP								
L	0.15	0.25	0.35	0.006	0.010	0.014	0.15	0.25	0.35	0.006	0.010	0.014
Т							0.03	0.08	0.13	0.001	0.003	0.005
ECN: C-07431 – Rev. C, 06-Aug-07 DWG: 5935												



RECOMMENDED PAD LAYOUT FOR PowerPAK[®] SC75-6L Single



Dimensions in mm/(Inches)

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